

Industrial Photonics

Design of ARCs

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1 Introduction

In this assignment it is asked to study the reflectivity of a solar cell and design some anti-reflection coating (ARC) to improve the performance of the photovoltaic cell (PV). I expect a pretty high reflection, without coating, because the refractive index of the silicon is quite big compared with the one of air. The principle of work of ARCs is that if the reflected light that is reflected back at the first air/material interface has a phase shift of 180°, and the same amplitude as the reflected light at that same interface, the two wave cancel out, so that, at a certain wavelength, a null value of reflectivity can be achieved.

2 Assignment

The points to accomplish in this assignment are

- 1. compute the reflectivity for unpolarized light at $\theta = 0^{\circ}$ and at $\theta = 30^{\circ}$
- 2. design a single layer ARC (SLARC)
- 3. design a double layer ARC (DLARC) using SiO_2 and TiO_2
- 4. compare the reflectivity with the effective reflectivity accounting for the spectral irradiance of the typical sunlight.
- 5. analyze the impact of 2% tolerance on the layer thicknesses

3 Initialize the script

In order to compute the solutions of this assignment, i used a python script, that i will include in this document. The following is just the preamble of that script. The script is available at https://github.com/arielpriarone/IndustrialPhotonics/tree/main/Assignment1.

```
import matplotlib.pyplot as plt
    import matplotlib.colors as color
2
    import numpy as np
    import matplotlib
    import tikzplotlib
5
6
    def tikzplotlib_fix_ncols(obj):
        workaround for matplotlib 3.6 renamed legend's _ncol to_ncols, which breaks tikzplotlib
9
10
        if hasattr(obj, "_ncols"):
            obj._ncol = obj._ncols
12
        for child in obj.get_children():
13
            tikzplotlib_fix_ncols(child)
14
```

4 Reflectivity without ARC

4.1 $\theta = 0^{\circ}$

With normal incidence of the light, and considering the bulk silicon as infinite length transmission line, the reflectivity can be calculated as

$$R = \left(\frac{z_{\infty}^{si} - z_{\infty}^{air}}{z_{\infty}^{si} - z_{\infty}^{air}}\right)^{2} = \left(\frac{z_{0}/n_{si} - z_{0}/n_{air}}{z_{0}/n_{si} + z_{0}/n_{air}}\right)^{2} = \left(\frac{n_{air} - nsi}{n_{air} + nsi}\right)^{2}$$
(1)

To compute that, i used python:

```
# %% compute the reflectivity
n_si=3.8  # refraction coefficient of silicon
n_air=1  # refraction coefficient of air

R_{\theta=0^\circ}=((n_air-n_si)/(n_air+n_si))**2  # Normal incidence
```

the result is:

$$R = 0.3403$$

4.2 $\theta = 30^{\circ}$

In this case, we have to consider the two components (polarization) of the light. The reflection coefficients and the reflectivity are:

$$\Gamma^{p} = \frac{n_{air}\sqrt{n_{si}^{2} - n_{air}^{2}\sin^{2}\theta} - n_{si}^{2}\cos\theta}{n_{air}\sqrt{n_{si}^{2} - n_{air}^{2}\sin^{2}\theta} + n_{si}^{2}\cos\theta}$$
(2)

$$\Gamma^{s} = \frac{n_{air}\cos\theta - \sqrt{n_{si}^{2} - n_{air}^{2}\sin^{2}\theta}}{n_{air}\cos\theta + \sqrt{n_{si}^{2} - n_{air}^{2}\sin^{2}\theta}}$$

$$(3)$$

$$R^p = |\Gamma^p|^2 = 0.3921 \tag{4}$$

$$R^s = |\Gamma^s|^2 = 0.2883 \tag{5}$$

$$R = \text{mean}(R^p, R^s) = 0.3402 \tag{6}$$

the result are calculated using the following:

One thing to notice is that, on average, if we consider unpolarized light, at $\theta = 30^{\circ}$, we have almost the same reflectivity as with normal incidence.

5 ARC design - single layer

5.1 Wavelength

In order to design an ARC, a wavelength at which that ARC will be optimize is needed. Ideally, at that wavelength, the reflectivity will be exactly null. To decide at which wavelength perform the design, we can analyze where the most of the solar energy is concentrated. To do that, i plotted the AM1.5 standard irradiation:

```
# %% Sun tipical irradiance
    AM15_lambda=np.array([300, ...
                                        ])
                                                  # wavelength
2
    AM15_irr=np.array([0.0010205, ...
                                        1)
                                                  # irradiance
3
    fig, axs=plt.subplots()
5
    fig.tight_layout()
    axs.semilogx(AM15_lambda,AM15_irr)
    axs.set_xlabel('$\lambda$ [nm]')
    axs.set_ylabel('Irradiance [${W}/{(m^2\cdot nm))}$]')
9
    axs.grid(True, 'both')
10
    tikzplotlib.save('irradiance.tex',axis_width='0.9\\textwidth',axis_height ='6cm')
11
```

Looking at the standard sunlight irradiance spectrum in **Figure 1**, is possible to see that the most irradiance is at $\lambda = 495$ nm.

The simplest choice is to design the ARC at $\lambda_0 = 495$ nm

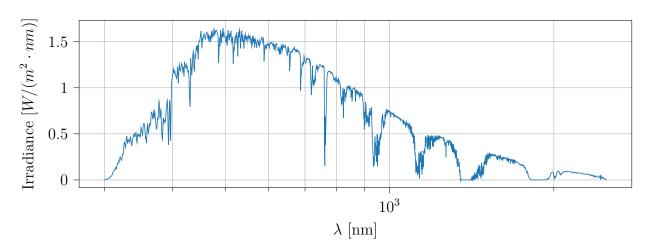


Figure 1: Typical irradiation spectrum of the sun

5.2 Design procedure

The working principle of a SLARC is to match the thickness of the layer with the quarter of the design wavelength λ_0 , in the layer medium. The ideal refractive index depends on the two mediums on the sides of the ARC, in this case air and silicon.

$$n_{ar} = \sqrt{n_{air}n_{si}} \tag{7}$$

$$\lambda_{ar} = \frac{\lambda_0}{n_{ar}} \tag{8}$$

$$d = \frac{\lambda_{ar}}{4} = 63.48 \text{nm} \tag{9}$$

 n_{ar} ideal refractive index, n_{si} refractive index of silicon, λ_{ar} design wavelength in the ARC medium.

Unfortunately, there is no material with the ideal refractive index, so the procedure is repeated considering some materials with similar refractive indeces: Al_2O_3 , Si_3N_4 , SiO_2 , TiO_2 .

```
# %% SLARC design
    lambda0=495 # design wavelength [nm]
    n_ideal=np.sqrt(n_air*n_si) # ideal refractive index at lambda0
3
    d_ideal=lambda0/4/n_ideal # ideal thickness
    n_TiO2= 2.7193
                                 # at 495 nm
5
    d_Ti02 = lambda0/4/n_Ti02
                                 # optimized for lambda0
6
    n_Si3N4 = 2.0647
                                 # at 495 nm
    d_Si3N4=lambda0/4/n_Si3N4
                                # optimized for lambda0
    n_{A1203} = 1.7747
                                 # at 495 nm
9
    d_Al203=lambda0/4/n_Al203 # optimized for lambda0
10
    n_Si02 = 1.4626
                                 # at 495 nm
11
    d_Si02=lambda0/4/n_Si02
                                 # optimized for lambda0
12
```

Compute the reflectivity - neglect chromatic dispersion 5.3

At this point we can study how the ARC is affecting the reflectivity. Neglecting the chromatic dispersion means to consider just one refractive index for all the wavelength. The problem can be formulated in computing the input reflection coefficient for the transmission line shown in **Figure 2**. Since we consider the silicon to be infinitely thick, $\Gamma_B^+=0$, $Z_B=Z_\infty^{si}$. And for normal incidence, $Z_{\infty}^{si} = Z_0/n_{si}$ and $Z_{\infty}^{ar} = Z_0/n_{ar}$.

$$\Gamma_B^- = \frac{Z_{\infty}^{si} - Z_{\infty}^{ar}}{Z_{\infty}^{si} + Z_{\infty}^{ar}}$$

$$\Gamma_A^+ = \Gamma_B^- e^{-2j \cdot k \cdot d}$$
(10)

$$\Gamma_A^+ = \Gamma_B^- e^{-2j \cdot k \cdot d} \tag{11}$$

$$Z_A = Z_{\infty}^{ar} \frac{1 + \Gamma_A^+}{1 - \Gamma_A^+} \tag{12}$$

$$\Gamma_A^- = \frac{Z_A - Z_\infty^{air}}{Z_A - Z_\infty^{air}} \tag{13}$$

This calculation are performed in the following script, and the result shown in **Figure 3**

```
# %% check reflectivity - no cromatic dispersion
fig, axs=plt.subplots()
fig.tight_layout()
```

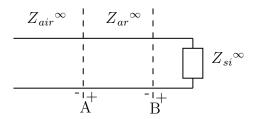


Figure 2: Equivalent TL

```
for n_ar, d in zip([n_ideal,n_Al203,n_Si3N4,n_Si02,n_Ti02],
                           [d_ideal,d_A1203,d_Si3N4,d_Si02,d_Ti02]):
                               Z0=120*np.pi
                                                                                                                                         # free space inpedance
  5
                               Z_{inf_ar}=Z0/n_ar
                                                                                                                                        # impedence of ARC
   6
                                                                                                                                        # impedence of bulk silicon
                               Z_inf_Si=Z0/n_si
                               Gbminus=(Z_inf_Si-Z_inf_ar)/(Z_inf_Si+Z_inf_ar) # reflection coefficient
                               K0=2*np.pi/lambdas
                               k=K0*n_ar
 10
                               Gaplus=(Gbminus*np.exp(-2j*k*d))
 11
                               Za=Z_inf_ar*(1+Gaplus)/(1-Gaplus)
 12
                               Gaminus=(Za-Z0)/(Za+Z0)
 13
                               R_vect=np.abs(Gaminus)**2*100
 14
                               axs.plot(lambdas,R_vect)
 15
                 axs.set_xlabel('$\lambda$ [nm]')
 16
                 axs.set_ylabel('Reflectivity [%]')
 17
                 axs.grid(True, 'both')
 18
 19
                 axs.minorticks_on()
                 axs.legend(['ideal $n=1.9493$', '$Al_20_3 \, n=1.7747$', '$Si_3N_4 \, n=2.0647$', '$Si0_2 \, n=1.7747$', '$Si0_3N_4 \, n=2.0647$', '$Si0_2 \, n=1.7747$', '$Si0_3N_4 \, n=2.0647$', 'Si0_3N_4 \, n=2.0647$', 'Si0_3
20
                  \rightarrow n=1.4626$', '$TiO_2 \, n=2.7193$'])
21
```

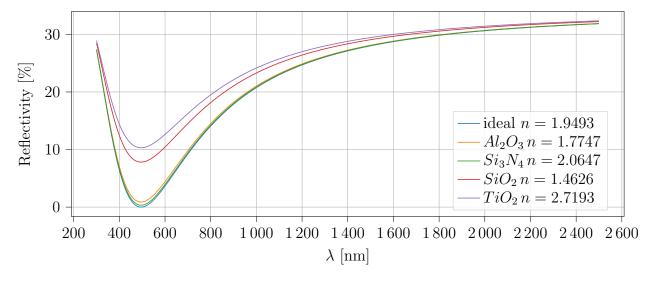


Figure 3: Different ARCs considering a single n

Looking at Figure 3 it is evident how the best match is the Si_3N_4 coating.

5.4 Compute the reflectivity - consider chromatic dispersion

In the assignment it was not required to account for the chromatic dispersion, but i wanted to see if it would have made a big difference. To do that i used the Sellmeier equations taken from [1][2], and from the website https://refractiveindex.info/.

$$n_{Al_2O_3}^2 - 1 = \frac{1.4313493\lambda^2}{\lambda^2 - 0.0726631^2} + \frac{0.65054713\lambda^2}{\lambda^2 - 0.1193242^2} + \frac{5.3414021\lambda^2}{\lambda^2 - 18.028251^2}$$
(14)

$$n_{Si_3N_4}^2 - 1 = \frac{3.0249\lambda^2}{\lambda^2 - 0.1353406^2} + \frac{40314\lambda^2}{\lambda^2 - 1239.842^2}$$
 (15)

$$n_{SiO_2}^2 - 1 = \frac{0.6961663\lambda^2}{\lambda^2 - 0.0684043^2} + \frac{0.4079426\lambda^2}{\lambda^2 - 0.1162414^2} + \frac{0.8974794\lambda^2}{\lambda^2 - 9.896161^2}$$
(16)

$$n_{TiO_2}^2 = 5.913 + \frac{0.2441}{\lambda^2 - 0.0803} \tag{17}$$

with this i considered the dependency of n on λ , and plotted the dispersion an shown in **Figure 4**. The script is the following:

```
# %% compute the chromatic dispersion
            n_ideal_v=n_ideal*lambdas/lambdas # ideal refractive index at lambda0
 2
            lambdas_um=lambdas/1000
            n_Ti02_v = (4.99+1/96.6*lambdas_um**(-1.1)+1/4.6*lambdas_um**(-1.95))**.5
                                                                                                                                                                                                                                                                                        # at every
              \hookrightarrow lambda
            n_Si3N4_v = (1+3.0249/(1-(0.1353406/lambdas_um)**2)+40314/(1-(1239.842/lambdas_um)**2))**.5
              \rightarrow # at every lambda
            n_{A}1203_{v} = (1+1.4313493/(1-(0.0726631/lambdas_um)**2)+0.65054713/(1-(0.1193242/lambdas_um)**2) + 0.65054713/(1-(0.1193242/lambdas_um)**2) + 0.65054
              \leftrightarrow +5.3414021/(1-(18.028251/lambdas_um)**2))**.5
                                                                                                                                                                                                         # at every lambda
            n_{si02v} = (1+0.6961663/(1-(0.0684043/lambdas_um)**2)+0.4079426/(1-(0.1162414/lambdas_um)**2)
              \rightarrow +0.8974794/(1-(9.896161/lambdas_um)**2))**.5
                                                                                                                                                                                                       # at every lambda
            fig, axs=plt.subplots()
 9
            fig.tight_layout()
10
            for n_ar in [n_ideal_v,n_A1203_v,n_Si3N4_v,n_Si02_v,n_Ti02_v]:
11
                        axs.plot(lambdas,n_ar)
12
             axs.set_xlabel('$\lambda$ [nm]')
13
             axs.set_ylabel('$n$')
14
             axs.grid(True, 'both')
15
            axs.minorticks_on()
16
            axs.legend(['ideal', '$Al_20_3$', '$Si_3N_4$', '$Si0_2$', '$Ti0_2$'])
17
```

And also computed the input reflectivity considering the chromatic dispersion. As evident in **Figure 5**, the effect of the varying refraction coefficient is negligible for Al_2O_3 and Si_3N_4 , but is quite visible for SiO_2 and TiO_2 .

The chosen design will be to use Si_3N_4 , with a thickness of 59.93nm, which gives a minimum reflectivity of about 0.33%.

The code to compute it is:

```
# %% check reflectivity - with dispersion

fig, axs=plt.subplots()
```

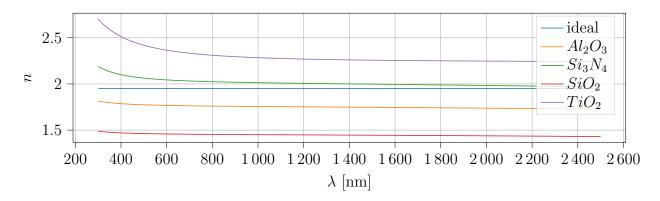


Figure 4: n dependency on λ

```
fig.tight_layout()
    for n_ar, d in zip([n_ideal_v,n_A1203_v,n_Si3N4_v,n_Si02_v,n_Ti02_v],
        [d_ideal,d_Al203,d_Si3N4,d_Si02,d_Ti02]):
        Z0=120*np.pi
                                      # free space inpedance
5
        Z_{inf_ar}=Z0/n_ar
                                      # impedence of ARC
        Z_inf_Si=Z0/n_si
                                      # impedence of bulk silicon
        Gbminus=(Z_inf_Si-Z_inf_ar)/(Z_inf_Si+Z_inf_ar) # reflection coefficient
        k=K0*n_ar
9
        Gaplus=(Gbminus*np.exp(-2j*k*d))
10
        Za=Z_inf_ar*(1+Gaplus)/(1-Gaplus)
11
        Gaminus=(Za-Z0)/(Za+Z0)
12
        R_vect=np.abs(Gaminus)**2*100
13
        if n_ar is n_Si3N4_v:
14
            R_SLARC=R_vect #save the best design
15
        axs.plot(lambdas,R_vect)
16
17
    axs.set_xlabel('$\lambda$ [nm]')
18
    axs.set_ylabel('Reflectivity [%]')
19
    axs.grid(True, 'both')
20
    axs.minorticks_on()
    axs.legend(['ideal', '$A1_20_3$', '$Si_3N_4$', '$Si0_2$', '$Ti0_2$'])
```

6 DLARC design - double layer

6.1 Silica/Titania layers

At this point the assignment ask to design a double layer ARC with silica and titania. I will follow the QWOT approach, fixing before the layer thicknesses. This were already calculated in the previous design.

$$d_{TiO_2} = 45.5$$
nm $d_{SiO_2} = 84.6$ nm

The remaining step is to compute the reflectivity with this new DLARC, that is equivalent to the TL shown in **Figure 6**.

The script is the following:

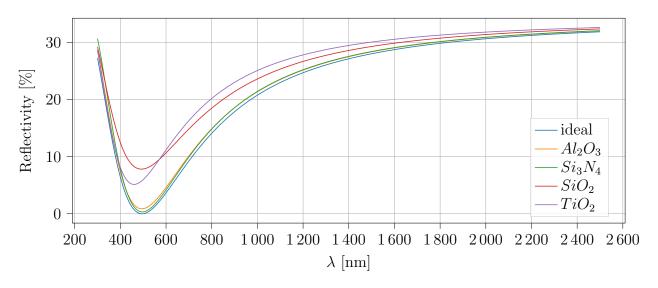


Figure 5: Different ARCs considering n dependency on λ

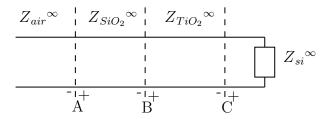


Figure 6: Equivalent TL - DLARC

```
# %% DLARC - SILICA/TITANIA
    Z_{inf_Si02}=Z0/n_Si02
2
    Z_{inf_Ti02=Z0/n_Ti02}
    Gcminus=(Z_inf_Si-Z_inf_Ti02)/(Z_inf_Si+Z_inf_Ti02)
    k=K0*n_dict['$Ti0_2$']
    Gbplus=Gcminus*np.exp(-2j*k*d_TiO2)
    Zb=Z_inf_TiO2*(1+Gbplus)/(1-Gbplus)
    Gbminus=(Zb-Z_inf_Si02)/(Zb+Z_inf_Si02)
    k=K0*n_dict['$Si0_2$']
9
    Gaplus=Gbminus*np.exp(-2j*k*d_SiO2)
10
    Za=Z_inf_Si02*(1+Gaplus)/(1-Gaplus)
11
    Gaminus=(Za-Z0)/(Za+Z0)
12
    R_DLARC_SiO2TiO2=np.abs(Gaminus)**2*100
13
```

6.2 Other materials layers

It was not requested from the assignment, but i was curious about if some materials were available with a more suitable refractive index ratios:

$$\frac{n_1}{n_2} = \sqrt{\frac{n_{air}}{n_{si}}} = 0.510$$

In order to understand that, i considered the materials in the **Table 1**, and computed the ratio for any combinations. The results are reported in **Figure 7**. It turned out that the pair of material

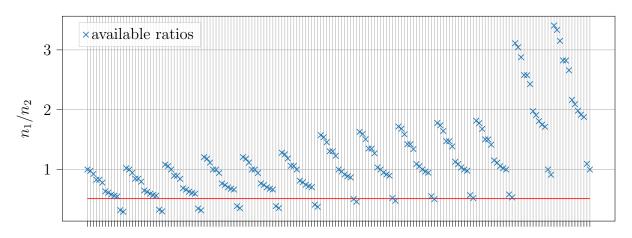
with most suitable ratio (red line reference) is Ta_2O_5 and Ge. The code to perform that is the following:

```
# %% DL ARC - some other materials
    n_dict={"$Na_3AlF_6$": 1.35,
2
             "$MgF_2$": 1.38,
             "$SiO_2$": 1.46,
             "$A1_20_3$": 1.629,
             "$CeF_3$": 1.63,
             "$PbF_2$": 1.73,
             "$Ta_20_5$": 2.126,
             "$ZrO_2$": 2.20,
             "$ZnS$": 2.32,
10
             "$TiO_2$": 2.40,
11
             "$Bi_20_3$": 2.45,
             "$Ge$": 4.2,
             "$Te$": 4.60}
14
15
    legend=[]; val=[]
16
    for keys_e, values_e in n_dict.items():
17
        for keys_i, values_i in n_dict.items():
18
             val.append(values_e/values_i)
19
             legend.append(keys_e + "//" + keys_i)
20
    fig, axs=plt.subplots()
21
    fig.tight_layout()
22
    axs.plot(legend, val, 'x')
23
    axs.hlines([(n_air/n_si)**0.5],legend[0],legend[-1],'red')
24
    axs.set_xlabel('Combination of materials')
25
    axs.set_ylabel('$n_1/n_2$')
26
    axs.grid(True, 'both')
27
    axs.legend(['available ratios', 'reference'])
28
```

material	n	material	n
Na_3AlF_6	1.35	ZrO_2	2.20
MgF_2	1.38	ZnS	2.32
SiO_2	1.46	TiO_2	2.40
Al_2O_3	1.62	Bi_2O_3	2.45
CeF_3	1.63	Ge	4.20
PbF_2	1.73	Te	4.60
Ta_2O_5	2.12	-	-

Table 1: Common materials refractive indeces

At this point the problem become similar to the previous one: design a DLARC with Ta_2O_5 and Ge, using QWOT approach, and than solve the TL in **Figure 8** for input reflectivity. The script is the following:



Combination of materials

Figure 7: Different materials n ratios

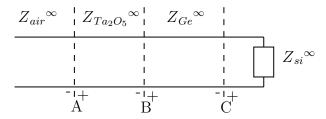


Figure 8: Equivalent TL - DLARC

```
# %% DLARC - Ta205 and Ge
    d_Ge=lambda0/4/n_dict['$Ge$']
2
    d_Ta=lambda0/4/n_dict['$Ta_20_5$']
3
    Z_inf_Ge=Z0/n_dict['$Ge$']
    Z_{inf_Ta=Z0/n_dict['$Ta_20_5$']}
    Gcminus=(Z_inf_Si-Z_inf_Ge)/(Z_inf_Si+Z_inf_Ge)
    k=K0*n_dict['$Ge$']
    Gbplus=Gcminus*np.exp(-2j*k*d_Ge)
    Zb=Z_inf_Ge*(1+Gbplus)/(1-Gbplus)
9
    Gbminus=(Zb-Z_inf_Ta)/(Zb+Z_inf_Ta)
10
    k=K0*n_dict['$Ta_20_5$']
11
    Gaplus=Gbminus*np.exp(-2j*k*d_Ta)
12
    Za=Z_inf_Ta*(1+Gaplus)/(1-Gaplus)
13
    Gaminus=(Za-Z0)/(Za+Z0)
14
    R_DLARC_Ta205Ge=np.abs(Gaminus)**2*100
```

6.3 Comparison of designs

At this point we can compare the reflectivity of the best SLARC design with Silica/Titania and Ta_2O_5/Ge DLARC designs. The script is the following, and the result are shown in **Figure 9**.

It's evident that the Ta_2O_5/Ge DLARC outperform both TiO_2/SiO_2 and Si3N4 coating at the design wavelength λ_0 , because it reaches almost zero reflectivity, but the reflectivity drop at λ_0 in a really narrow manner, w.r.t TiO_2/SiO_2 . This may imply that even is Ta_2O_5/Ge is best at λ_0 , TiO_2/SiO_2 could be best in average considering the whole useful sunlight spectrum.

```
# %% check reflectivity - SLARC / DLARCS

fig, axs=plt.subplots()

fig.tight_layout()

axs.semilogy(lambdas,R_DLARC_SiO2TiO2)

axs.semilogy(lambdas,R_DLARC_Ta2O5Ge)

axs.semilogy(lambdas,R_SLARC)

axs.set_xlabel('$\lambda$ [nm]')

axs.set_ylabel('Reflectivity [%]')

axs.grid(True,'both')

axs.minorticks_on()

axs.legend(['DLARC $TiO2 \,/\, SiO2$','DLARC $Ta_2O_5 \,/\, Ge$','SLARC $Si_3N_4$'])
```

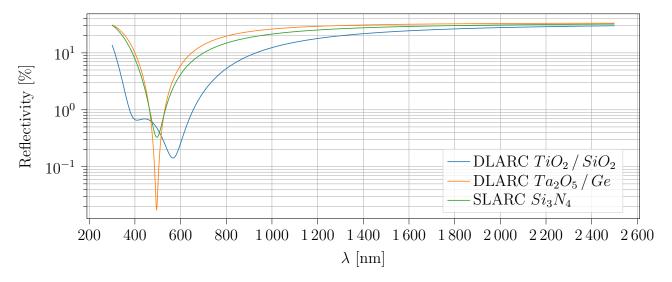


Figure 9: Reflectivity for different designs

7 Effective reflectivity

In the evaluation of the performance, up to now, we neglected the actual power distribution of the sunlight. To account for that it is possible to compute the effective reflectivity, defined as:

$$R_{eff} = \frac{\int_{\lambda_{min}}^{\lambda_{max}} R(\lambda) \cdot N(\lambda) d\lambda}{\int_{\lambda_{min}}^{\lambda_{max}} N(\lambda) d\lambda}$$
(18)

 $R(\lambda)$ is the spectral reflectivity already calculated, and $N(\lambda)$ is the standard solar spectrum already considered in **Figure 1**. As usual the calculation is carried out in python, and the result are collected in the **Table 2**.

```
# %% check effective reflectivity
indx=0
R_eff=[]; R_min=[]
for R in [R_DLARC_SiO2TiO2, R_DLARC_Ta205Ge, R_SLARC]:
NUM=0; DEN=0
for _ in lambdas:
```

```
if indx is (len(lambdas)-2):
    break

NUM+=R[indx]*AM15_irr[indx]*(lambdas[indx+1]-lambdas[indx])

DEN+=AM15_irr[indx]*(lambdas[indx+1]-lambdas[indx])

R_eff.append(NUM/DEN)

R_min.append(np.min(R))

print(R_eff);print(R_min)
```

ARC	SiO_2/TiO_2	Ta_2O_5/Ge	Si_3N_4
R_{eff}	13.775 %	30.979 %	30.664 %
R_{min}	0.142~%	0.017~%	0.328~%

Table 2: Min and effective reflectivity

Now, with this new data, it is clear that the best design is the SiO_2/TiO_2 DLARC, because even if it doesn't have the best minimum reflectivity, on average, it has the lowest where the most solar power is distributed.

8 Tolerances

The SiO_2/TiO_2 DLARC has to be manufactured with some technique, so the problem of the tolerance of manufacturing become relevant. In the **Figure 10**, we consider how the two different deviation from the nominal value affect the reflectivity. As usual this is the code for the computations:

```
# %% DLARC - tolerance effect
    Z_{inf}Si02=Z0/n_dict['$Si0_2$']
    Z_inf_Ti02=Z0/n_dict['$Ti0_2$']
    Gcminus=(Z_inf_Si-Z_inf_Ti02)/(Z_inf_Si+Z_inf_Ti02)
    k=K0*n_dict['$Ti0_2$']
    fig, axs=plt.subplots()
    fig.tight_layout()
    legend=[]
    for err1 in [-0.02, 0.02]:
        for err2 in [-0.02, 0.02]:
10
            Gbplus=Gcminus*np.exp(-2j*k*d_TiO2*(1-err1))
11
            Zb=Z_inf_TiO2*(1+Gbplus)/(1-Gbplus)
12
            Gbminus=(Zb-Z_inf_Si02)/(Zb+Z_inf_Si02)
13
            k=K0*n_dict['$Si0_2$']
            Gaplus=Gbminus*np.exp(-2j*k*d_SiO2*(1-err2))
15
16
            Za=Z_inf_SiO2*(1+Gaplus)/(1-Gaplus)
            Gaminus=(Za-Z0)/(Za+Z0)
17
            R_DLARC_tolerance=np.abs(Gaminus)**2*100
18
            axs.plot(lambdas,R_DLARC_tolerance)
19
            legend.append('$TiO_2$ ('+str(err1)+'\%), $SiO_2$ ('+str(err2)+'\%)')
20
    axs.plot(lambdas,R_DLARC_SiO2TiO2)
21
    legend.append('$Ti0_2$, $Si0_2$ nominal tickness')
22
    axs.minorticks_on()
23
```

```
24 axs.set_xlabel('$\lambda$ [nm]')
25 axs.set_ylabel('Reflectivity [%]')
26 axs.grid(True,'both')
27 axs.legend(legend,loc='lower right')
```

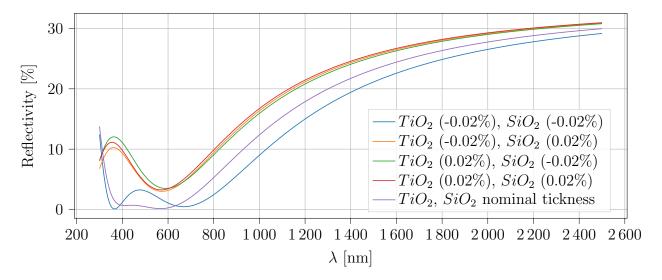


Figure 10: Reflectivity for different manufacture deviations

References

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- [2] KEVIN LUKE, YOSHITOMO OKAWACHI, MICHAEL R. E. LAMONT, ALEXANDER L. GAETA, and MICHAL LIPSON. Broadband mid-infrared frequency comb generation in a Si3N4 microresonator. *Optics Letters*, 40(21), 2015.